

Dual N-channel 60 V, 12.5 mOhm logic level MOSFET inLFPAK56D using Repetitive Avalanche technology2 December 2020Product data sheet

1. General description

Dual, logic level N-channel MOSFET in an LFPAK56D package, using Application Specific (ASFET) repetitive avalanche silicon technology. This product has been designed and qualified to AEC-Q101 for use in repetitive avalanche applications.

2. Features and benefits

- Fully automotive qualified to AEC-Q101 at 175 °C
 - Repetitive Avalanche rated to 30 °C T_i rise:
 - Tested to 1 Bn avalanche events
- LFPAK copper clip package technology:
 - High robustness and reliability
 - Gull wing leads for high manufacturability and AOI

3. Applications

- 12 V, 24 V and 48 V automotive systems
- Repetitive avalanche topologies
- Engine control
- Transmission control
- Actuator and auxiliary loads

4. Quick reference data

Table 1. Quick reference data								
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	60	V	
I _D	drain current	V _{GS} = 5 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	40	А	
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	64	W	
Static characte	eristics FET1 and FET2			•				
R _{DSon}	drain-source on-state resistance	V _{GS} = 5 V; I _D = 10 A; T _j = 25 °C; <u>Fig. 14</u>		6.1	10	12.5	mΩ	
Dynamic characteristics FET1 and FET2								
Q _{GD}	gate-drain charge	$I_{D} = 10 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 5 \text{ V}; T_{j} = 25 \text{ °C}; Fig. 16; Fig. 17$		-	7.9	-	nC	

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5. Pinning information

Table 2	Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	S1	source1	8 7 6 5	D1 D1 D2 D2					
2	G1	gate1							
3	S2 source2								
4	G2	gate2							
5	D2	drain2							
6	D2	drain2		S1 G1 S2 G2					
7	D1	drain1		mbk725					
8	D1	drain1	LFPAK56D; Dual LFPAK (SOT1205)						

6. Ordering information

Table 3. Ordering information						
Type number						
	Name	Description	Version			
BUK9K13-60RA	LFPAK56D; Dual LFPAK	plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205			

7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK9K13-60RA	91360RA

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	60	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	60	V
V _{GS}	gate-source voltage	DC; T _j ≤ 175 °C		-10	10	V
		Pulsed; T _j ≤ 175 °C	[1] [2]	-15	15	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	64	W
I _D	drain current	V _{GS} = 5 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	40	А
		V _{GS} = 5 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	33	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	190	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
I _S	source current	T _{mb} = 25 °C		-	40	А

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Symbol	Parameter	Conditions		Min	Max	Unit
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	190	A
Avalanche rug	gedness		•			·
E _{DS(AL)R}	repetitive drain-source avalanche energy	$ \begin{array}{l} I_D = 1.92 \text{ A}; \ V_{sup} \leq 60 \ V; \ R_{GS} = 10 \ \Omega; \ V_{GS} \\ = 10 \ V; \ T_{j(rise)} \leq 30 \ ^\circ\text{C}; \ unclamped; \ \overline{\text{Fig. 4}}; \\ \hline \text{Fig. 5}; \ \overline{\text{Fig. 6}} \end{array} $	[3] [4] [5]	-	75.2	mJ
Avalanche Ru	ggedness FET1 and FET2					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ I_D = 40 \text{ A}; \text{V}_{sup} \leq 60 \text{ V}; \text{R}_{GS} = 50 \Omega; \\ \text{V}_{GS} = 5 \text{ V}; \text{T}_{j(init)} = 25 ^\circ\text{C}; \text{ unclamped}; \\ \hline \text{Fig. 7} $	[6] [7]	-	82	mJ

[1] Accumulated Pulse duration up to 50 hours delivers zero defect ppm

[2] Significantly longer life times are achieved by lowering T_i and or V_{GS} .

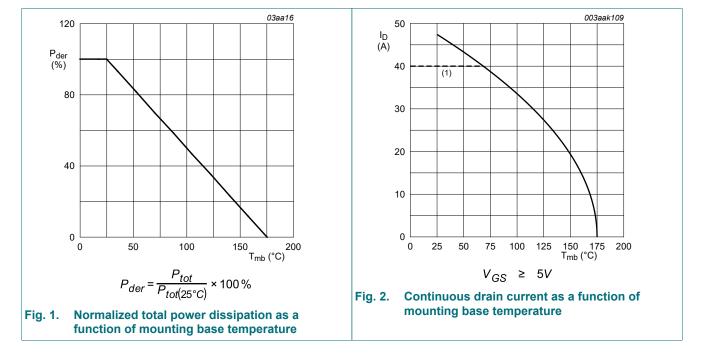
[3] Repetitive avalanche rating is limited by maximum junction temperature of 175 °C and junction rise of 30 °C

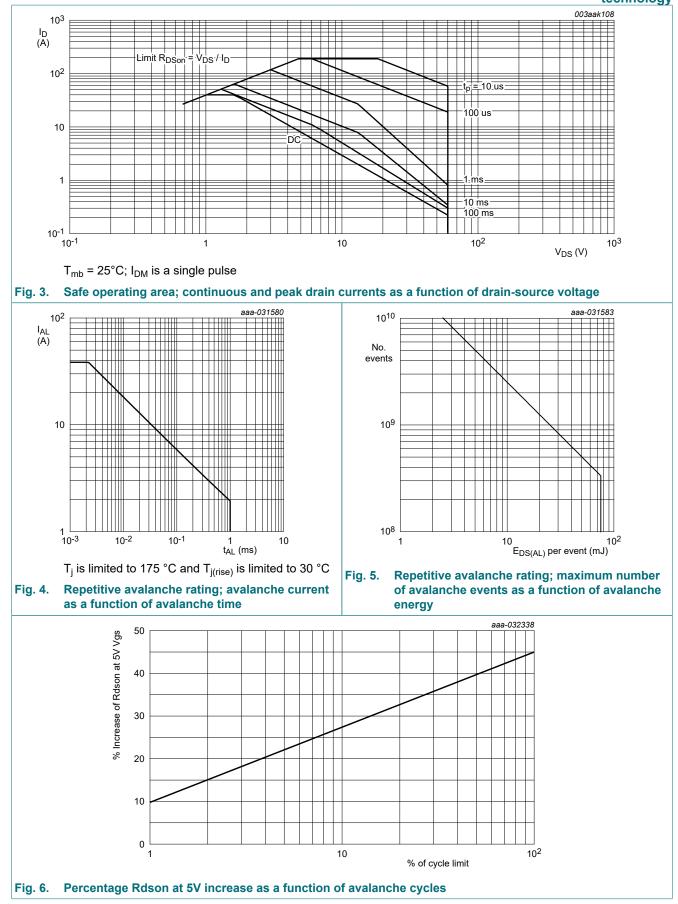
[4] Refer to Fig. 5 for the limiting number of avalanche events

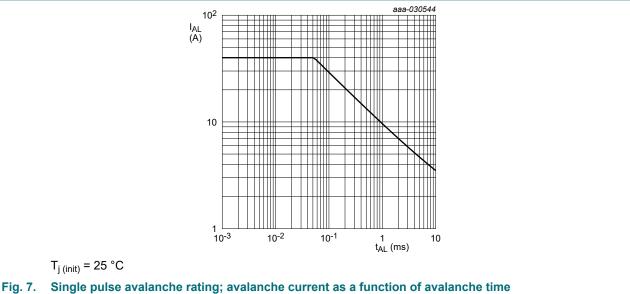
[5] Refer to Fig. 6 Rdson at Vgs=5V will increase as a function of repetitive avalanche cycles

[6] Refer to application note AN10273 for further information

[7] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C



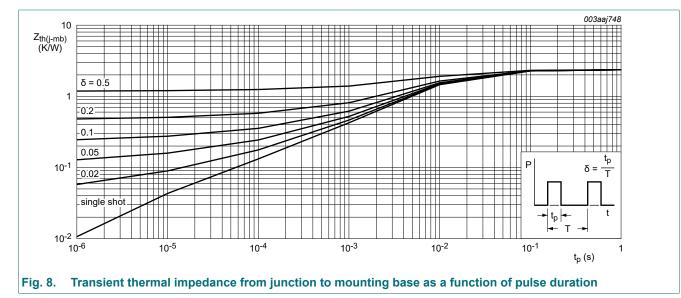




9. Thermal characteristics

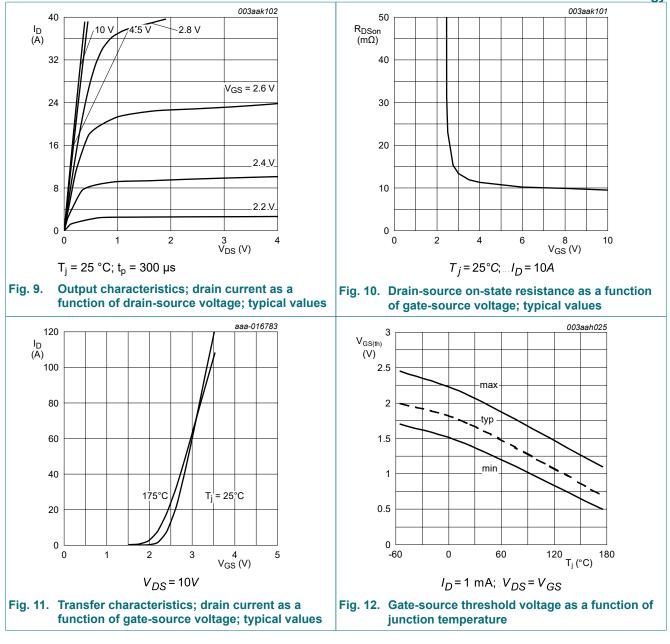
Table 6. Thermal characteristics

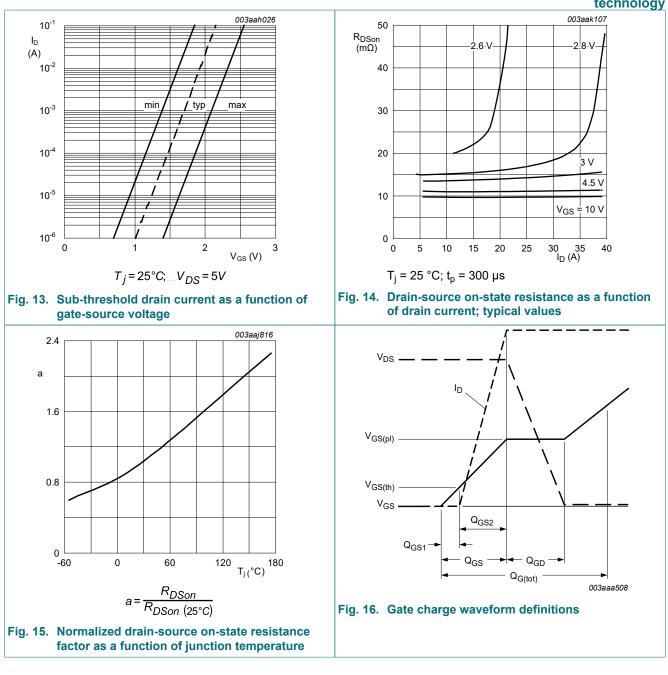
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 8</u>	-	-	2.36	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board	-	95	-	K/W

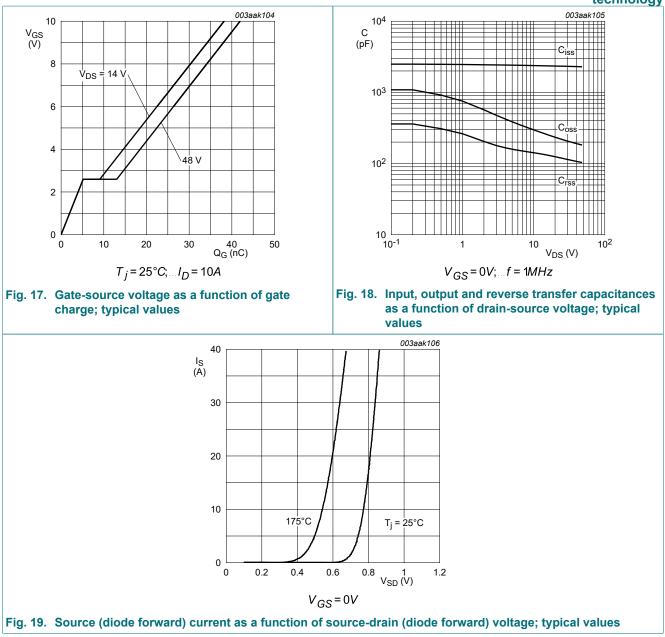


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics FET1 and FET2			-		
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	54	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ °C}; Fig. 12;$ Fig. 13	1.4	1.7	2.1	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 12	0.5	-	-	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 12</u>	-	-	2.45	V
DSS	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	0.02	1	μA
		V _{DS} = 60 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state	V _{GS} = 5 V; I _D = 10 A; T _j = 25 °C; <u>Fig. 14</u>	6.1	10	12.5	mΩ
	resistance	V _{GS} = 5 V; I _D = 10 A; T _j = 175 °C; Fig. 14; Fig. 15	-	22	28.3	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; Fig. 14	5.4	9	11.2	mΩ
Dynamic ch	naracteristics FET1 and FE	T2				
Q _{G(tot)}	total gate charge	I _D = 10 A; V _{DS} = 48 V; V _{GS} = 5 V;	-	22.4	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 16; Fig. 17</u>	-	5.2	-	nC
Q _{GD}	gate-drain charge	1	-	7.9	-	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;	-	2215	2953	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 18</u>	-	225	270	pF
C _{rss}	reverse transfer capacitance		-	116	159	pF
t _{d(on)}	turn-on delay time	V_{DS} = 48 V; R _L = 5 Ω; V _{GS} = 5 V;	-	13	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	22.1	-	ns
t _{d(off)}	turn-off delay time]	-	30.5	-	ns
t _f	fall time] [-	21.8	-	ns
Source-drai	in diode FET1 and FET2					
V _{SD}	source-drain voltage	I _S = 10 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 19</u>	-	0.78	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 10 \text{ A}; dI_{S}/dt = -100 \text{ A}/\mu s; V_{GS} = 0 \text{ V};$	-	22.7	-	ns
Q _r	recovered charge	V _{DS} = 30 V; T _j = 25 °C	-	18.9	-	nC

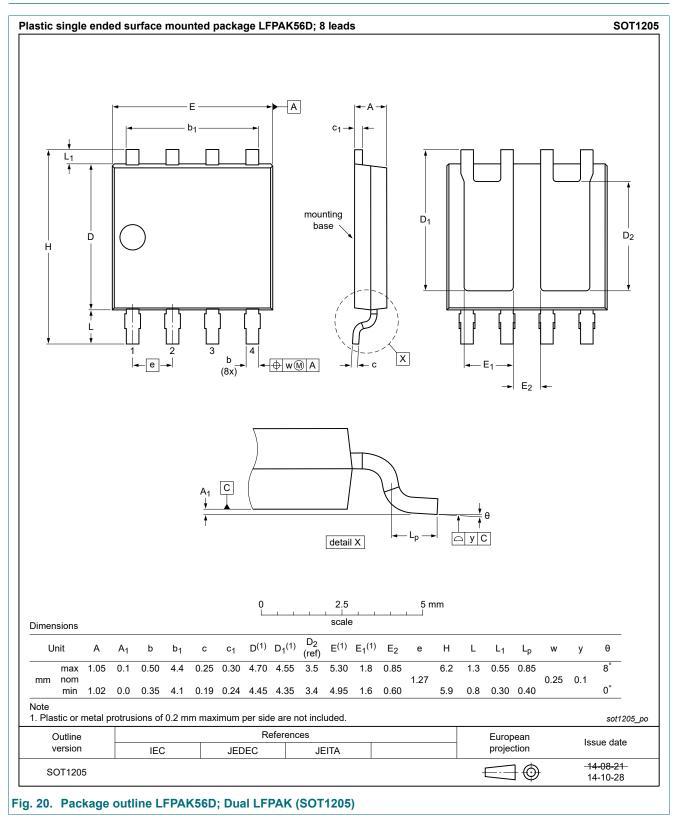






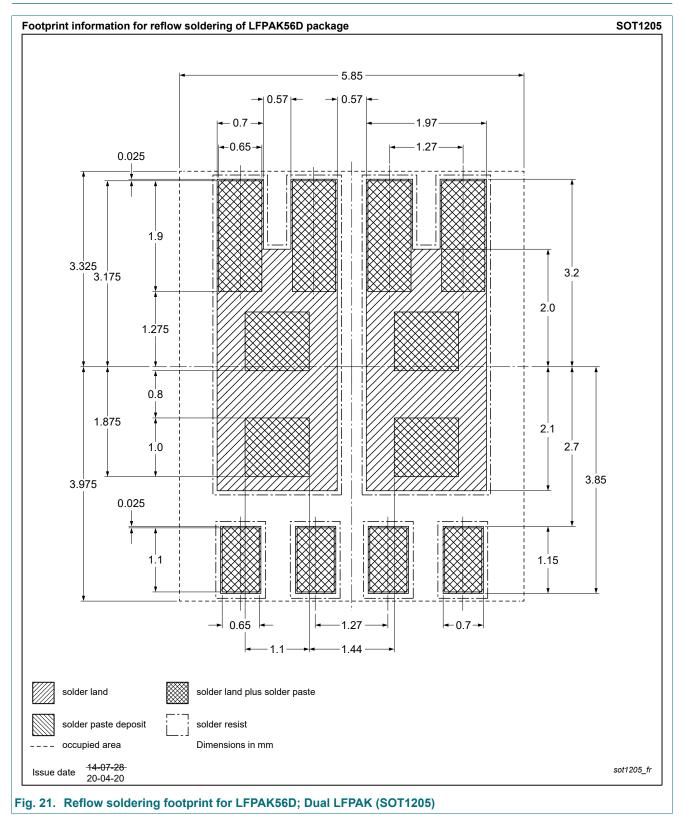
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11. Package outline



Dual N-channel 60 V, 12.5 mOhm logic level MOSFET in LFPAK56D using Repetitive Avalanche technology

12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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